

REVISIONS																		
LTR	DESCRIPTION										DATE (YR-MO-DA)				APPROVED			
E	Change to vendor similar part number for vendor CAGE number 61772 for devices 08KX, 09KX, 10KX, 11KX, 12KX, 13KX, 14KX, 15KX, and 16KX. Remove vendor CAGE number 61772 from devices 08YX, 09YX, 10YX, 11YX, 12YX, 13YX, 15YX, and 16YX. Change to vendor similar part number for vendor CAGE number 65786 for devices 09 and 11. Add vendor CAGE number 50088 to the drawing as a source of supply for devices 04JX and 05JX. Add vendor CAGE number 65896 to the drawing as a source of supply for devices 15 and 16. Removed 4.3.3 from drawing. Editorial changes throughout.										92-04-27				M. A. FRYE			

THE ORIGINAL FIRST PAGE OF THIS DRAWING HAS BEEN REPLACED.

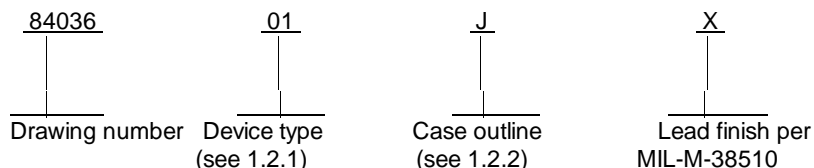
CURRENT CAGE CODE 67268

REV																		
SHEET																		
REV	E	E	E	E	E	E	E	E	E	E	E							
SHEET	14	15	16	17	18	19	20	21	22	23	24							
REV STATUS OF SHEETS				REV			E	E	E	E	D	E	E	E	E	E	E	E
				SHEET			1	2	3	4	5	6	7	8	9	10	11	12
PMIC N/A				PREPARED BY James E. Jamison							DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444							
STANDARDIZED MILITARY DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Ray Monnin														
				APPROVED BY Don Cool														
				DRAWING APPROVAL DATE 84-08-23														
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											SIZE A		CAGE CODE 14933		84036			
											SHEET 1 OF 24							

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-Jan devices".

1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number 1/	Supply voltage variation	Address access time
01		10%	200 ns (synchronous)
02		10%	90 ns
03		10%	90 ns
04		10%	150 ns
05		10%	200 ns
06		10%	70 ns
07		10%	120 ns (synchronous)
08		10%	45 ns
09		10%	45 ns
10		10%	55 ns
11		10%	55 ns
12		10%	70 ns
13		10%	70 ns
14		10%	35 ns
15		10%	120 ns
16		10%	90 ns

1.2.2 Case outline(s). The case outline(s) shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
J	D-3 (24-lead, 1.290" x .610" x .225"), dual-in-line package
K	F-6 (24-lead, .640" x .420" x .090"), flat package
L	D-9 (24-lead, 1.280" x .310" x .200"), dual-in-line package
X	C-12 (32-terminal, .560" x .458" x .120"), rectangular chip carrier package
Y	Figure 1, (24-lead, .308" x .408"), rectangular chip carrier package
Z	C-12 (32-terminal, .560" x .458" x .120"), rectangular chip carrier package with castellated instead of chamfered corners and extended pad metallization at terminal number 1.
3	C-4 (28-terminal, .460" x .460" x .100"), square chip carrier package

1/ Generic numbers are listed on the standardized military drawing source approval bulletin at the end of this document and will also be listed in MIL-BUL-103.

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1.3 Absolute maximum ratings.

Supply voltage range (V_{CC}) -0.3 V dc to +7.0 V dc 2/
 Temperature under bias -55°C to +125°C
 Storage temperature range -55°C to +150°C
 Maximum power dissipation (P_D) 1.0 W
 Lead temperature (soldering, 5 seconds) +275°C
 Thermal resistance, junction-to-case (Θ_{JC}): See MIL-M-38510, appendix C
 Case Y 30°C/W
 Junction temperature (T_J) +150°C 3/
 All input or output voltages with respect to ground -0.3 V dc to V_{CC} +0.3 V dc 4/

1.4 Recommended operating conditions.

Case operating temperature range (T_C) -55°C to +125°C
 Input low voltage (V_{IL}):
 Device types 01 through 16 -0.3 V dc to 0.8 V dc 2/
 Input high voltage (V_{IH}):
 Device types 01, 07 2.4 V dc to V_{CC} +0.3 V dc 2/
 Device types 02 through 06, 08 through 16 2.2 V dc to V_{CC} +0.3 V dc 2/
 Supply voltage range (V_{CC}): 4.5 V dc to 5.5 V dc 2/
 Minimum chip enable low time 40 ns 5/
 Minimum chip enable high time 40 ns 5/
 Maximum input rise time 40 ns
 Maximum input fall time 40 ns

2. APPLICABLE DOCUMENTS

2.1 Government specification, standard, and bulletin. Unless otherwise specified, the following specification, standard, and bulletin of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

(Copies of the specification, standard, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2/ All voltages referenced to V_{SS} .

3/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.

4/ Negative undershoots to a minimum of -3.0 V are allowed with a maximum of 20 ns pulse width.

5/ For device types 02, 03, and 06 only.

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2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.2 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Truth table. The truth table shall be as specified on figure 3.

3.2.4 Block diagram. The block diagrams shall be as specified on figure 4.

3.2.5 Die overcoat. Polyimide and silicone coatings are allowable as an overcoat on the die for alpha particle protection provided that each coated microcircuit inspection lot (see MIL-M-38510) shall be subjected to and pass the internal moisture content test (method 1018 of MIL-STD-883), the frequency of the internal water vapor testing may not be decreased unless approved by the preparing activity.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103 (see 6.6 herein).

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.9 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ 2/ $V_{SS} = 0\text{ V}, 4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
High level output voltage	V_{OH}	$I_{OH} = -1\text{ mA}$	1, 2, 3	01-07, 15,16	2.4		V
		$I_{OH} = -4\text{ mA}$	1, 2, 3	08-14			
Low level output voltage	V_{OL}	$I_{OL} = 3.2\text{ mA}$	1, 2, 3	01,07		0.4	V
		$I_{OL} = 4.0\text{ mA}$		02,03, 06,15			
		$I_{OL} = 2.0\text{ mA}$		04,05,16			
		$I_{OL} = 8.0\text{ mA}$	1, 2, 3	08-14			
High impedance output leakage current	I_{OLZ} I_{OHZ}	$\overline{OE} = V_{IH}$	1, 2, 3	01,02 06,07	-1.0	1.0	μA
				04,05,09, 11,13,14, 15,16	-10.0	10.0	
				03,08, 10,12	-5.0	5.0	
Input leakage current	I_{IL} I_{IH}	$V_{IN} = \text{GND}$ $V_{IN} = 5.5\text{ V}$	1, 2, 3	01,02, 06,07	-1.0	1.0	μA
				04,05,15	-2.0	2.0	
				03,08,10, 12,16	-5.0	5.0	
				09,11, 13,14	-10.0	10.0	
Operating supply current	I_{CC1}	$V_{CC} = 5.5\text{ V}, f = f_{\text{max}}$ 3/ $\overline{CE} = V_{IL}$, outputs open All other inputs at V_{IL}	1, 2, 3	01,07		10	mA
				04,05,13, 15,16		90	
				02,03,06		70	
				08,10,12		85	
				09,11		120	
				14		150	
Standby supply current	I_{CC2}	$\overline{CE} = \overline{WE} = V_{IH}, I_O = 0$	1, 2, 3	02,03,06		8	mA
				04,05		10	
				10,12, 15,16		15	
				09,11, 13,14		25	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> $V_{SS} = 0 \text{ V}, 4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ $-55^{\circ} \text{ C} \leq T_C \leq +125^{\circ} \text{ C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Standby supply current	I_{CC3}	$\overline{CE} = V_{CC} - 0.3 \text{ V}, I_O = 0$	1, 2, 3	<u>06,07</u>		50	μA
				<u>01,02</u>		100	
				<u>04,05</u>		250	
				<u>03,08,10, 12,15,16</u>		900	
				<u>13</u>		10	mA
				<u>09,11,14</u>		20	mA
Data retention supply current	I_{CC4}	$\overline{CE} = V_{CC}, V_{CC} = 2.0 \text{ V}$	1, 2, 3	<u>01,02</u>		50	μA
				<u>04,05</u>		100	
				<u>08,10,12, 15,16</u>		200	
				<u>03</u>		300	
				<u>06,07</u>		25	
Input <u>4/</u> capacitance	C_I	$V_I = V_{CC}$ or GND, $f = 1 \text{ MHz}$ See 4.3.1c	4	All		10	pF
Output <u>4/</u> capacitance	C_O	$V_{IO} = V_{CC}$ or GND, $f = 1 \text{ MHz}$ See 4.3.1c	4	All		12	pF
Read/write cycle time	t_{AVAV}	<u>5/ 6/</u>	9,10,11	<u>01</u>	280		ns
				<u>02,03,16</u>	90		
				<u>04</u>	150		
				<u>05</u>	200		
				<u>15</u>	120		
				<u>07</u>	170		
				<u>08,09</u>	45		
				<u>10,11</u>	55		
				<u>06,12,13</u>	70		
				<u>14</u>	35		

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> $V_{SS} = 0 \text{ V}, 4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ $-55^{\circ} \text{ C} \leq T_C \leq +125^{\circ} \text{ C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Address access time	t_{AVQV}	<u>5/ 6/</u>	9,10,11	<u>01</u>		200	ns
				<u>02,03,16</u>		90	
				<u>04</u>		150	
				<u>05</u>		200	
				<u>07,15</u>		120	
				<u>08,09</u>		45	
				<u>10,11</u>		55	
				<u>06,12,13</u>		70	
				<u>14</u>		35	
Output hold after address change <u>4/</u>	t_{AVQX}	<u>5/ 6/</u>	9,10,11	<u>15,16</u>	0		ns
				<u>04,05</u>	10		
				<u>02,03,06, 07,08-14</u>	5		
Output enable to output active <u>4/</u>	t_{OLQX}	<u>5/ 6/</u>	9,10,11	<u>01,07</u>	10		ns
				<u>02,03,06, 08,12,13</u>	5		
				<u>04,05,09, 11,14,15, 16</u>	0		
Output enable access time	t_{OLQV}	<u>5/ 6/</u>	9,10,11	<u>01,07,15</u>		80	ns
				<u>02,03,16</u>		65	
				<u>04</u>		60	
				<u>05</u>		70	
				<u>08,09</u>		25	
				<u>10,11</u>		40	
				<u>06,12,13</u>		50	
				<u>14</u>		20	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> $V_{SS} = 0 \text{ V}, 4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ $-55^{\circ} \text{ C} \leq T_C \leq +125^{\circ} \text{ C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Chip enable to output active <u>4/</u>	t_{ELQX}	<u>5/ 6/</u>	9,10,11	<u>01,07</u>	10		ns
				<u>02,03,06, 08-14</u>	5		
				<u>04,05, 15,16</u>	0		
Chip enable access time	t_{ELQV}	<u>5/ 6/</u>	9,10,11	<u>01</u>		200	ns
				<u>02,03,16</u>		90	
				<u>04</u>		150	
				<u>05</u>		200	
				<u>07,15</u>		120	
				<u>08,09</u>		45	
				<u>10,11</u>		55	
				<u>06,12,13</u>		70	
				<u>14</u>		35	
Chip enable to output in high Z <u>4/</u>	t_{EHQZ}	<u>5/ 6/</u>	9,10,11	<u>01</u>		80	ns
				<u>02,03,07, 15,16</u>		50	
				<u>04,05</u>		60	
				<u>08,09</u>		25	
				<u>10,11</u>		30	
				<u>06,12,13</u>		35	
				<u>14</u>		15	
Write recovery time	$t_{WHA V}$	<u>5/ 6/</u>	9,10,11	<u>02,03,04, 05,06,15, 16</u>	10		ns
				<u>09,11,14</u>	0		

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> $V_{SS} = 0 \text{ V}$, $4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ $-55^{\circ} \text{ C} \leq T_C \leq +125^{\circ} \text{ C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Chip enable to end-of-write	t_{ELWH}	<u>5/ 6/</u>	9,10,11	<u>01</u>	200		ns
				<u>02,03,16</u>	55		
				<u>04</u>	90		
				<u>05,07</u>	120		
				<u>06</u>	45		
				<u>08,09,14</u>	30		
				<u>10-13</u>	40		
				<u>15</u>	70		
Address valid to end-of-write	t_{AVWH}	<u>5/ 6/</u>	9,10,11	<u>02,03, 12,13</u>	65		ns
				<u>04</u>	100		
				<u>05</u>	130		
				<u>15</u>	105		
				<u>06</u>	50		
				<u>08,09,14</u>	30		
				<u>10,11</u>	45		
				<u>16</u>	80		
Address to $\overline{\text{WE}}$ setup time	t_{AVWL}	<u>5/ 6/</u>	9,10,11	<u>02-06, 15,16</u>	10		ns
				<u>07,08,09, 11,14</u>	0		
				<u>10</u>	5		
				<u>12,13</u>	15		
Address to $\overline{\text{CE}}$ setup time	t_{AVEL}	<u>5/ 6/</u>	9,10,11	01,07	0		ns

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> $V_{SS} = 0 \text{ V}, 4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ $-55^{\circ} \text{ C} \leq T_C \leq +125^{\circ} \text{ C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Output enable to output in high Z <u>4/</u>	t_{OHQZ}	<u>5/ 6/</u>	9,10,11	<u>01</u>		80	ns
				<u>02,03, 15,16</u>		40	
				<u>04,07</u>		50	
				<u>05</u>		60	
				<u>08,09</u>		25	
				<u>10,11</u>		30	
				<u>06,12,13</u>		35	
				<u>14</u>		15	
Write enable pulse width	t_{WLWH}	<u>5/ 6/</u>	9,10,11	<u>01</u>	200		ns
				<u>02,03,16</u>	55		
				<u>04</u>	90		
				<u>05,07</u>	120		
				<u>15</u>	70		
				<u>08,11</u>	25		
				<u>06,10, 12,13</u>	40		
				<u>09,14</u>	20		
Data setup to end-of-write	t_{DVWH}	<u>5/ 6/</u>	9,10,11	<u>01</u>	80		ns
				<u>02,03,06, 12,13,16</u>	30		
				<u>04,07</u>	50		
				<u>05</u>	70		
				<u>08,09</u>	20		
				<u>10,11</u>	25		
				<u>15</u>	35		
				<u>14</u>	15		

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions ^{1/ 2/} $V_{SS} = 0\text{ V}$, $4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Data hold after end-of-write	t_{WHDX}	<u>5/ 6/</u>	9,10,11	<u>01,06,07</u>	10		ns
				<u>02,03,04, 05,15,16</u>	15		
				<u>08,09, 11,14</u>	0		
				<u>10,12,13</u>	5		
Minimum chip-enable high time after write	t_{EHEL}	<u>5/ 6/</u>	9,10,11	<u>01</u>	80		ns
				<u>07</u>	50		
Address <u>hold</u> time after CE low	t_{ELAX}	<u>5/ 6/</u>	9,10,11	<u>01</u>	50		ns
				<u>07</u>	30		
Chip-enable pulse width during write	t_{ELEH}	<u>5/ 6/</u>	9,10,11	<u>01</u>	200		ns
				<u>07</u>	120		
Write enable pulse setup time	t_{WLEH}	<u>5/ 6/</u>	9,10,11	<u>01</u>	200		ns
				<u>02,03,16</u>	55		
				<u>04</u>	90		
				<u>05,07</u>	120		
				<u>08</u>	30		
				<u>06,10, 12,13</u>	40		
				<u>09,14</u>	20		
				<u>11</u>	25		
				<u>15</u>	70		

^{1/} All voltages referenced to V_{SS} .^{2/} Negative undershoots to a minimum of -0.3 V are allowed with a maximum of 20 ns pulse width.^{3/} $f_{\text{max}} = 1/t_{\text{AVAV}}$ ^{4/} Tested initially, and after any design or process change which could affect these parameters.^{5/} AC measurements assume transition time $\leq 5\text{ ns}$ and input levels are from V_{SS} to 3.0 V. Output load is specified on figure 5. Reference timing levels are at 1.5 V.^{6/} For timing waveforms, see figure 6.

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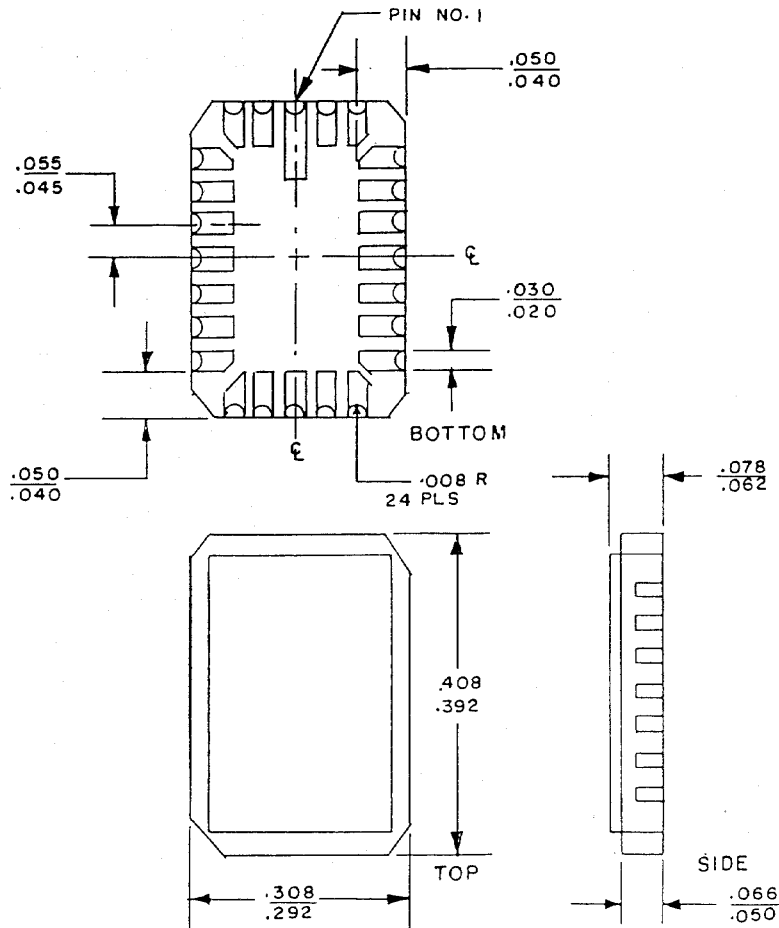
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24 PIN RECTANGULAR LEADLESS CHIP CARRIER



NOTES:

1. Dimensions are in inches.
2. Metric equivalents are for general information only.

FIGURE 1. Case outline Y (24-lead, .308 x .408", rectangular chip carrier package).

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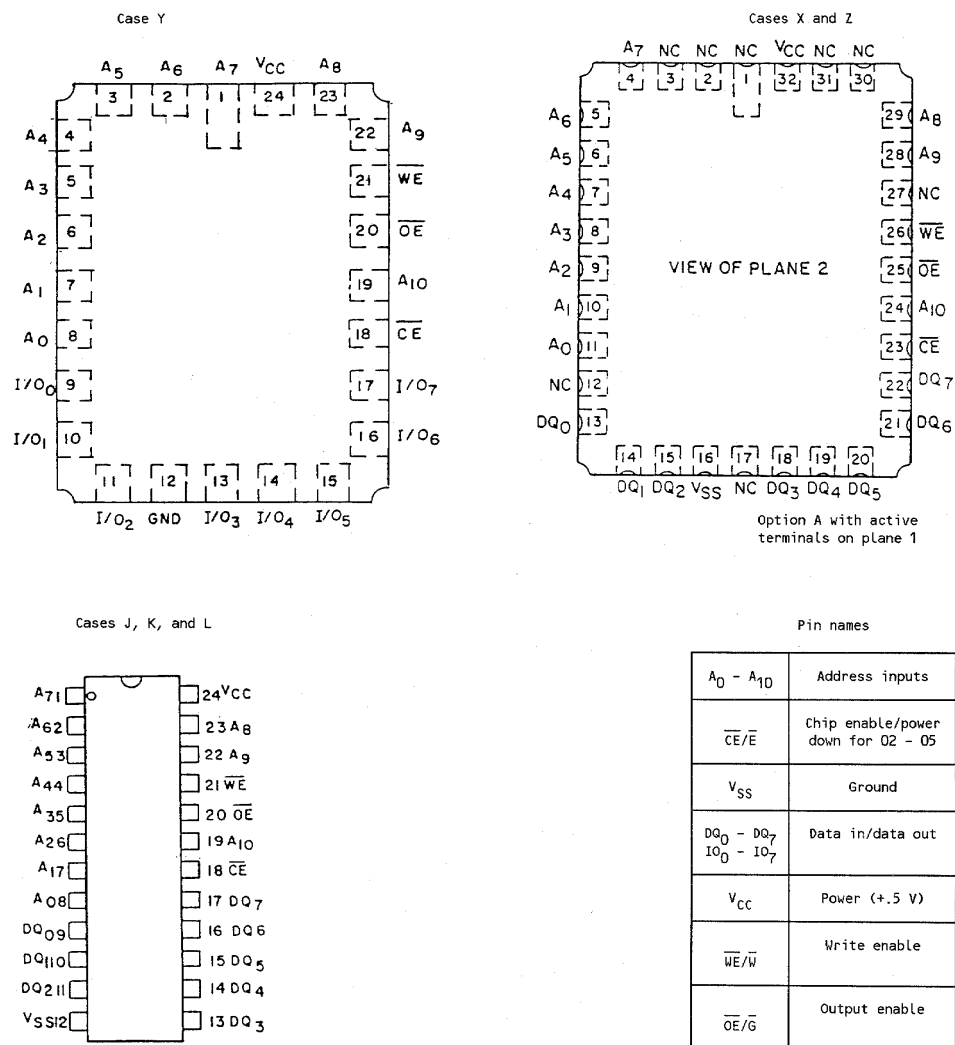


FIGURE 2. Terminal connections.

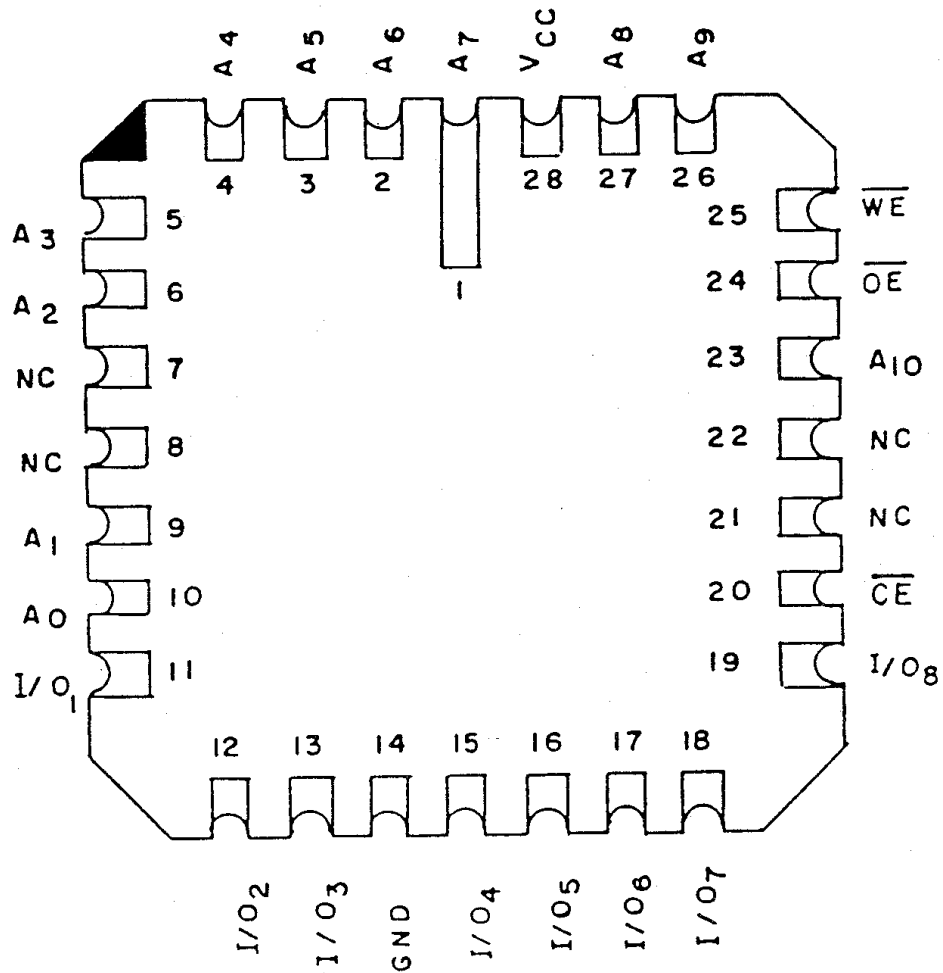
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FIGURE 2. Terminal connection. - Continued

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Device types 01 and 07

Read cycle

Time reference	Inputs					Function
	\overline{CE}	\overline{WE}	\overline{OE}	A	DQ	
-1	H	X	X	X	Z	Memory disabled
0	↓	H	X	V	Z	Cycle begins, addresses are latched
1	L	H	L	X	X	Output enabled
2	L	H	L	X	V	Output valid
3	↑	H	X	X	V	Read accomplished
4	H	X	X	X	Z	Prepare for next cycle (same as -1)
5	↓	H	X	V	Z	Cycle ends, next cycle begins (same as 0)

Write cycle

Time reference	Inputs					Function
	\overline{CE}	\overline{WE}	\overline{OE}	A	DQ	
-1	H	X	H	X	X	Memory disabled
0	↓	X	H	✓	X	Cycle begins, addresses are latched
1	L	L	H	X	X	Write period begins
2	L	↑	H	X	✓	Data is written
3	↑	H	H	X	X	Write completed
4	H	X	H	X	X	Prepare for next cycle (same as -1)
5	↓	X	H	V	X	Cycle ends, next cycle begins (same as 0)

Device types 02 - 06 and 08 - 16

\overline{CE}	\overline{OE}	\overline{WE}	Mode	DQ
V_{IH}	X	X	Deselect	High Z
V_{IL}	X	V_{IL}	Write	D_{IN}
V_{IL}	V_{IL}	V_{IH}	Read	D_{OUT}
V_{IL}	V_{IH}	V_{IH}	Read	High Z

X = Don't care

FIGURE 3. Truth table.

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Device types 01 and 07.

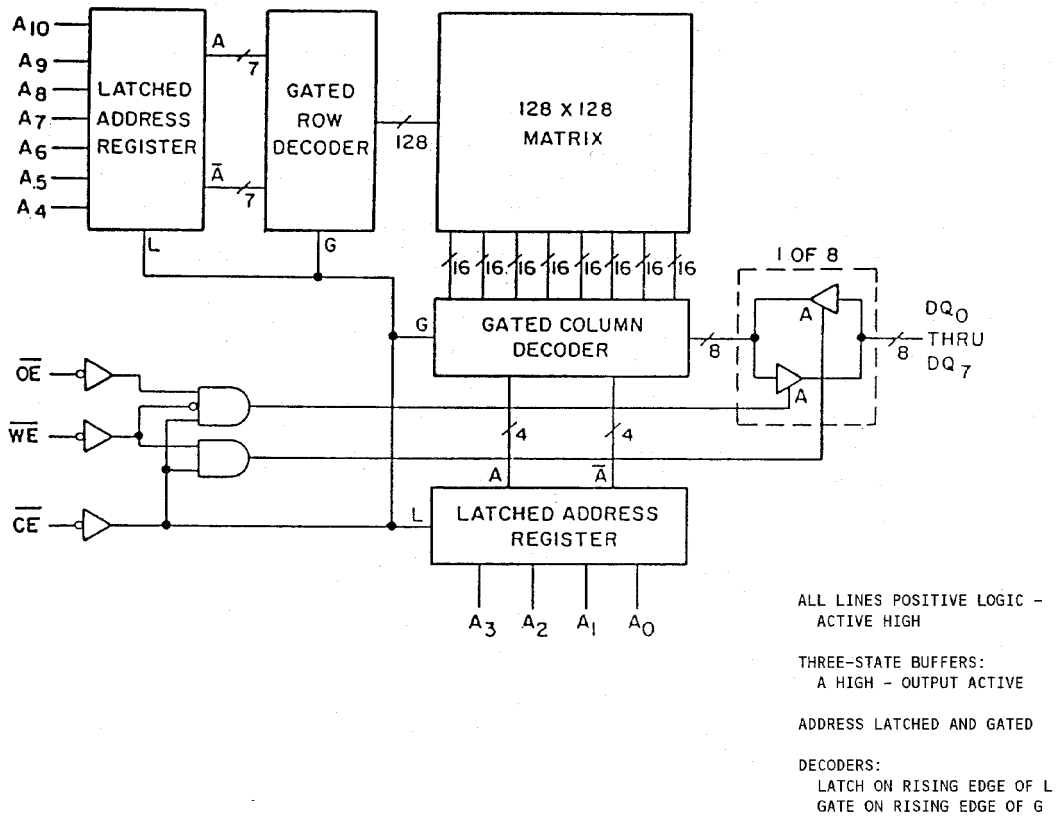


FIGURE 4. Block diagram.

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Device types 02 - 06 and 08 - 16

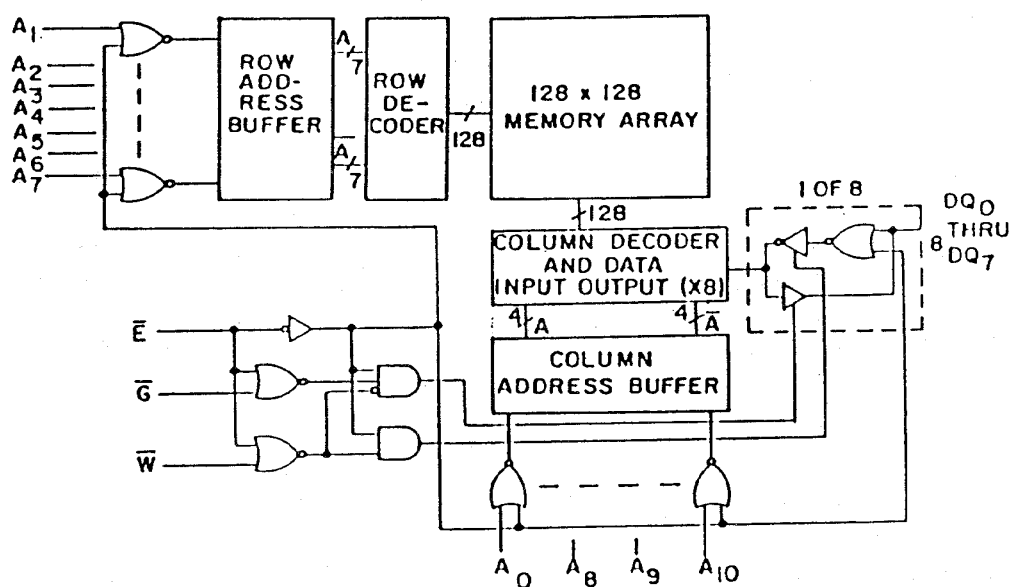


FIGURE 4. Block diagram - Continued.

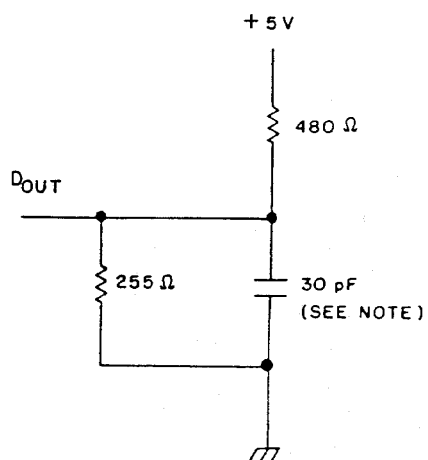
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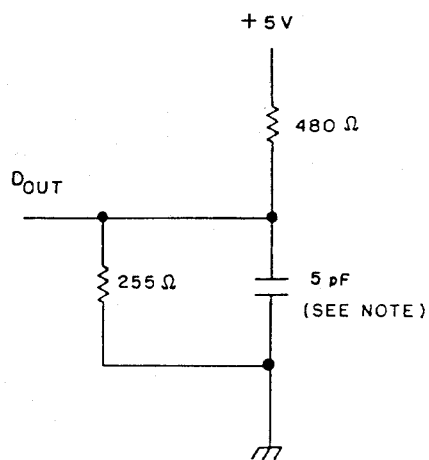
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Circuit A or equivalent circuit

For all other switching parameters.



Circuit B or equivalent circuit

for t_{OLQX} , t_{ELQX} , t_{EHQZ} ,
and t_{OHQZ} .

NOTE:

1. Including scope and jig capacitance.

FIGURE 5. Output loading.

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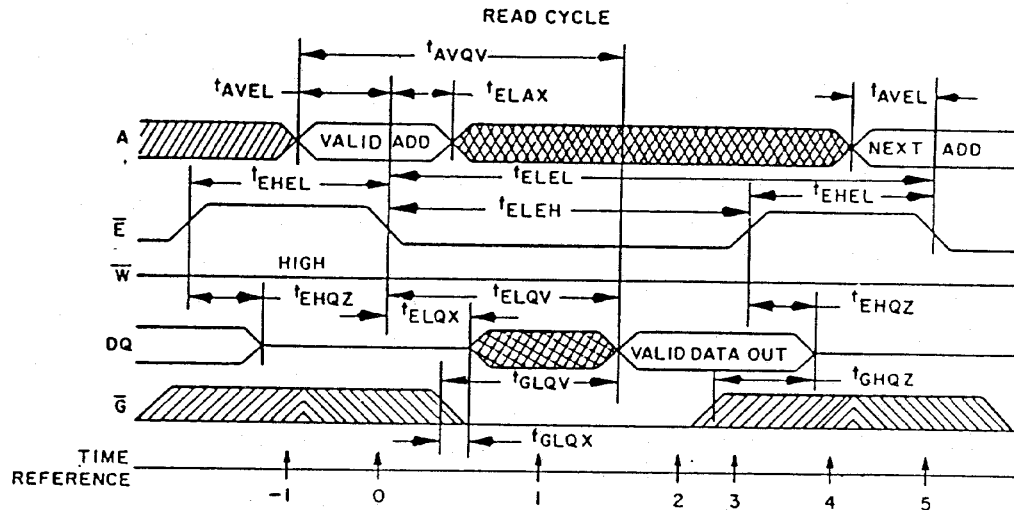
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Device types 01 and 07

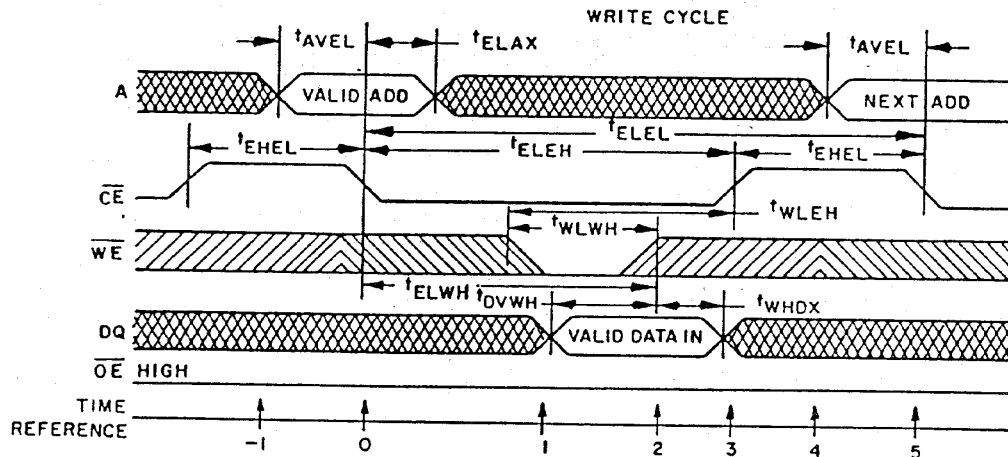


The address information is latched in the on chip registers on the falling edge of CE ($t = 0$), minimum address setup and hold time requirements must be met. After the required hold time, the address may change state without affecting device operation. During time ($t = 1$), the outputs become enabled but data is not valid until time ($t = 2$), WE must remain high throughout the readcycle. After the data has been read, CE may return high ($t = 3$). This will force the output buffers into a high impedance mode at time ($t = 4$). OE is used to disable the output buffers when in a logical "1" state ($t = -1, 0, 3, 4, 5$). After ($t = 4$) time, the memory is ready for the next cycle.

FIGURE 6. Timing waveforms.

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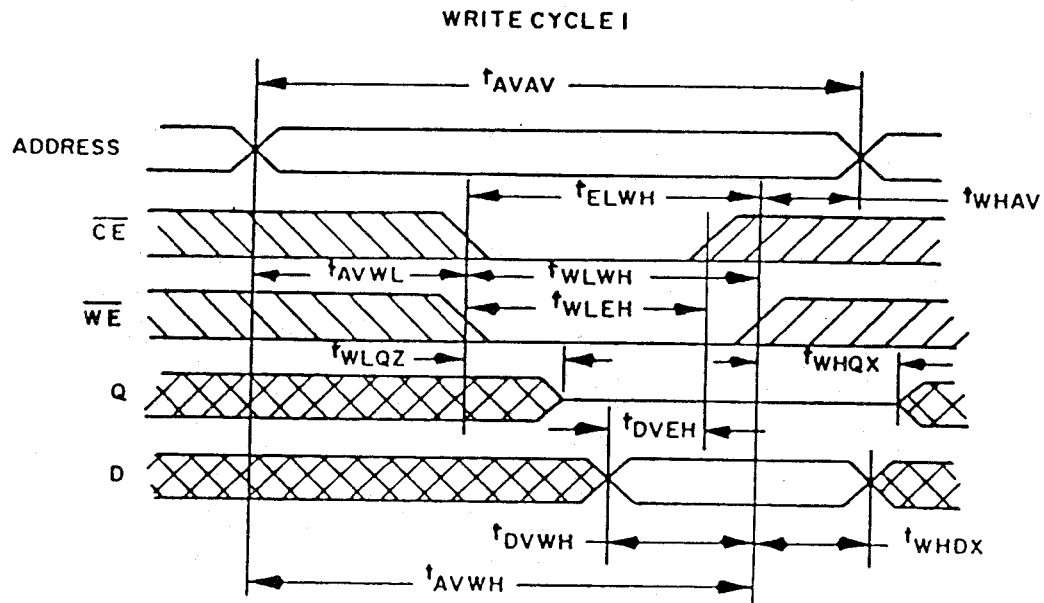
Device types 01 and 07



The write cycle is initiated on the falling edge of \overline{CE} ($t = 0$), which latches the address information in the on-chip registers. If a write cycle is to be performed where the outputs are not to become active, \overline{OE} can be held high (inactive). Parameter t_{DVWH} and t_{WHDX} must be met for proper device operation regardless of \overline{OE} . If \overline{CE} and \overline{OE} fall before \overline{WE} falls (read mode), a possible bus conflict may exist. If \overline{CE} rises before \overline{WE} rises, reference data setup and hold times to the \overline{CE} rising edge. The write operation is terminated by the first rising edge of \overline{WE} ($t = 2$) or \overline{CE} ($t = 3$). After the minimum \overline{CE} high time (t_{EHEL}), the next cycle may begin. If a series of consecutive write cycles are to be performed, the \overline{WE} line may be held low until all desired locations have been written. In this case, data setup and hold times must be referenced to the rising of \overline{CE} .

FIGURE 6. Timing waveforms - Continued.

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NOTE: G is low throughout write cycle.

To write, addresses must be stable, \overline{CE} low and \overline{WE} falling low for a period no shorter than t_{WLWH} . Data is referenced with the rising edge of \overline{WE} or \overline{CE} whichever occurs first (t_{DVWH} and t_{WHDX}). While addresses are changing, \overline{WE} must be high. When \overline{WE} falls low, the I/O pins are still in the output state for a period of t_{WLOZ} and input data of the opposite phase to the outputs must not be applied (bus contention). If \overline{CE} transitions low simultaneously with \overline{WE} line transitioning low or after the \overline{WE} transition, the output will remain in a high impedance state. \overline{OE} is held continuously low.

FIGURE 6. Timing waveforms - Continued.

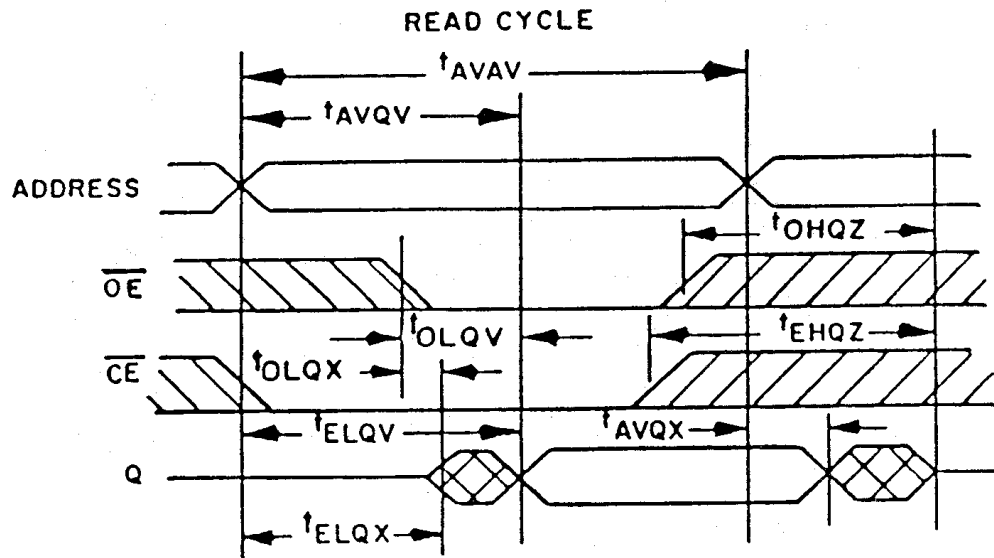
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NOTE: W is high for a read cycle.

Addresses must remain stable for the duration of the read cycle. To read, \overline{OE} and \overline{CE} must be $\leq V_{IL}$ and $WE \geq V_{IH}$. The output buffers can be controlled independently by OE while CE is low. To execute consecutive read cycles, CE may be tied low continuously until all desired locations are accessed. When CE is low, addresses must be driven by stable logic levels and must not be in the high impedance state.

FIGURE 6. Timing waveforms - Continued.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4, 7, 8 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 7, 9

* PDA applies to subgroup 1.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition D using the circuit submitted with the certificate of compliance (see 3.6 herein).

(2) $T_A = +125^\circ\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Test shall be as specified in table II herein.

b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for the initial test and after process or design changes which may affect capacitance. Sample size is 15 devices with no failures, and all input and output terminals tested.

d. Subgroup 7 and 8 tests shall include verification of the truth table.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test conditions, method 1005 of MIL-STD-883.

(1) Test condition D using the circuit submitted with the certificate of compliance (see 3.6 herein).

(2) $T_A = +125^\circ\text{C}$, minimum.

(3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Replaceability is determined as follows:

- a. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- b. When a QPL source is established, the part numbered device specified in this drawing will be replaced by the microcircuit identified as part number M38510/2910XB--.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.4 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-ECS, telephone (513) 296-6047.

6.5 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone (513) 296-5377.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECS.

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STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN

DATE: 92-04-27

Approved sources of supply for SMD 5962-84036 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-ECS. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Military drawing PIN	Vendor CAGE number	Vendor 1/ similar PIN	Replacement military specification PIN
8403601JX	34371	HM1-6516/883	M38510/29102BJX
8403601ZX	34371	HM4-6516/883	M38510/29102BZX
8403602JX	34371	HM1-65162/883	M38510/29104BJX
8403602ZX	34371	HM4-65162/883	M38510/29104BZX
8403603JX	34371	HM1-65162C/883	
8403603ZX	34371	HM4-65162C/883	
8403604JX	50088 2/	MKB6116P-82 SMJ5517-15JDM	M38510/29101BJX
8403604ZX	2/	SMJ5517-15FGM	M38510/29101BZX
8403605JX	50088 2/	MKB6116P-83 SMJ5517-20JDM	M38510/29105BJX
8403605ZX	2/	SMJ5517-20FGM	M38510/29105BZX
8403606JX	34371	HM1-65162B/883	
8403606ZX	34371	HM4-65162B/883	
8403607JX	34371	HM1-6516B/883	
8403607ZX	34371	HM4-6516B/883	
8403608JX	61772	IDT6116LA45DB	
8403608XX	61772	IDT6116LA45L32B	
8403608LX	61772	IDT6116LA45TDB	
8403608KX	61772	IDT6116LA45EB	
84036083X	61772	IDT6116LA45L28B	
8403608YX	2/	IDT6116LA45L24B	
8403609JX	61772 65786	IDT6116SA45DB CY6116A-45DMB	

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN - Continued

Military drawing PIN	Vendor CAGE number	Vendor <u>1</u> / similar PIN	Replacement military specification PIN
8403609XX	65786 61772	CY6117A-45LMB IDT6116SA45L32B	
8403609LX	01295 61772 65786	SMJ68CE16S-45JDM IDT6116SA45TDB CY7C128A-45DMB	
8403609KX	61772 65786	IDT6116SA45EB CY7C128-45KMB	
84036093X	61772 65786	IDT6116SA45L28B CY6116A-45LMB	
8403609YX	<u>2</u> / 65786	IDT6116SA45L24B CY7C128A-45LMB	
8403610JX	61772	IDT6116LA55DB	
8403610XX	61772	IDT6116LA55L32B	
8403610LX	61772	IDT6116LA55TDB	
8403610KX	61772	IDT6116LA55EB	
84036103X	61772	IDT6116LA55L28B	
8403610YX	<u>2</u> / 65786	IDT6116LA55L24B	
8403611JX	61772 65786	IDT6116SA55DB CY6116A-55DMB	
8403611XX	65786 61772	CY6117A-55LMB IDT6116SA55L32B	
8403611LX	01295 61772 65786	SMJ68CE16S-55JDM IDT6116SA55TDB CY7C128A-55DMB	
8403611KX	61772 65786	IDT6116SA55EB CY7C128A-55KMB	
84036113X	61772 65786	IDT6116SA55L28B CY6116A-55LMB	
8403611YX	<u>2</u> / 65786	IDT6116SA55L24B CY7C128A-55LMB	
8403612JX	61772	IDT6116LA70DB	
8403612XX	61772	IDT6116LA70L32B	
8403612LX	61772	IDT6116LA70TDB	

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN - Continued

Military drawing PIN	Vendor CAGE number	Vendor <u>1</u> / similar PIN	Replacement military specification PIN
8403612KX	61772	IDT6116LA70EB	
84036123X	61772	IDT6116LA70L28B	
8403612YX	<u>2</u> /	IDT6116LA70L24B	
8403613JX	61772	IDT6116SA70DB	
8403613XX	61772	IDT6116SA70L32B	
8403613LX	61772	IDT6116SA70TDB	
8403613KX	61772	IDT6116SA70EB	
84036133X	61772	IDT6116SA70L28B	
8403613YX	<u>2</u> /	IDT6116SA70L24B	
8403614LX	01295 65786	SMJ68CE16S-35JDM CY7C128A-35DMB	
8403614JX	65786	CY6116A-35DMB	
8403614XX	65786	CY6117A-35LMB	
8403614YX	65786	CY7C128A-35LMB	
84036143X	65786	CY6116A-35LMB	
8403614KX	65786	CY7C128A-35KMB	
8403615JX	65896 61772	L6116HMB120 IDT6116LA120DB	
8403615XX	65896 61772	L6116TMB120 IDT6116LA120L32B	
8403615LX	65896 61772	L6116CMB120 IDT6116LA120TDB	
8403615KX	65896 61772	L6116FMB120 IDT6116LA120EB	
84036153X	65896 61772	L6116KMB120 IDT6116LA120L28B	
8403615YX	65896 <u>2</u> /	L6116TMB IDT6116LA120L24B	
8403616JX	65896 61772	L6116HMB90 IDT6116LA90DB	

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN - Continued

Military drawing PIN	Vendor CAGE number	Vendor <u>1/</u> similar PIN	Replacement military specification PIN
8403616XX	65896 61772	L6116TMB90 IDT6116LA90L32B	
8403616LX	65896 61772	L6116CMB90 IDT6116LA90TDB	
8403616KX	65896 61772	L6116FMB90 IDT6116LA90EB	
84036163X	65896 61772	L6116KMB90 IDT6116LA90L28B	
8403616YX	65896 <u>2/</u>	L6116TMB IDT6116LA90L24B	

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

2/ No longer available from this approved source.

Vendor CAGE
number

Vendor name
and address

01295

Texas Instruments Inc.
13500 N. Central Expressway
P. O. Box 655303
Dallas, TX 75265
Point of contact:
I-20 at FM 1788
Midland, TX 79711-0448

34371

Harris Semiconductor
P. O. Box 883
Melbourne, FL 32901

50088

SGS-Thomson microelectronics (3)
1310 Electronics Drive
Carrollton, TX 75006

61772

Integrated Device Technology
3236 Scott Blvd
Santa Clara, CA 95054

65786

Cypress Semiconductor Corporation
3901 N. First Street
San Jose, CA 95134-1599

65896

Logic Devices Incorporated
628 East Evelyn Avenue
Sunnyvale, CA 94086